RELIABILITY REPORT

FOR

MAX1652EEE

PLASTIC ENCAPSULATED DEVICES

March 25, 2002

MAXIM INTEGRATED PRODUCTS

120 SAN GABRIEL DR.

SUNNYVALE, CA 94086

Written by

Jim Pedicord
Quality Assurance
Reliability Lab Manager

Reviewed by

Bryan J. Preeshl
Quality Assurance
Executive Director

Conclusion

The MAX1652 successfully meets the quality and reliability standards required of all Maxim products. In addition, Maxim's continuous reliability monitoring program ensures that all outgoing product will continue to meet Maxim's quality and reliability standards.

Table of Contents

I. Device Description

A. General

The MAX1652 is a high-efficiency, pulse-width-modulated (PWM), step-down DC-DC controller in a small QSOP packages. The MAX1652 achieves up to 96% efficiency and delivers up to 10A using a unique Idle Mode synchronous-rectified PWM control scheme. This device automatically switches between PWM operation at heavy loads and pulse-frequency-modulated (PFM) operation at light loads to optimize efficiency over the entire output current range.

The device operates with a selectable 150kHz/300kHz switching frequency, which can also be synchronized to an external clock signal. Both external power switches are inexpensive N-channel MOSFETs, which provide low resistance while saving space and reducing cost.

The MAX1652 has an additional feedback pin that permits regulation of a low-cost second output tapped from a transformer winding and provides an additional positive output.

The MAX1652 has a 4.5V to 30V input voltage range with an output range of 2.5V to 5.5V.

B. Absolute Maximum Ratings

Item	Rating
V_+ to GND	-0.3V to +36V
GND to PGND	-0.3V to +0.3V
VL to GND	-0.3Vto +6.0V
BST to GND	-0.3V to +36V
DH to LX	-0.3V to (BST + 0.3V)
LX to BST	-6V to +0.3V
/SHDN to GND	-0.3V to (V+ +0.3V)
SYNC,SS,REF,SECFB,/SKIP,FB to GND	-0.3V to (VL +0.3V)
DL to PGND	-0.3V to (VL +0.3V)
CSH,CSL to GND	-0.3V to +6V
VL Output Current	+50mA to -1mA
REF Output Current	+5mA to –1mA
REF Short Circuit to GND	Continuous
Storage Temp.	-65°C to +160°C
Operating Temperature Range	-40°C to +85°C
Lead Temp. (10 sec.)	+300°C
Continuous Power Dissipation (TA = +70°C)	
16-Pin QSOP	667mW
Derates above +70°C	
16-Pin QSOP	8.3mW/°C

II. Manufacturing Information

A. Description/Function:	High Efficiency, PWM, Step-Down DC-DC Controller
B. Process:	S12 – Silicon Gate 1.2 micron CMOS
C. Number of Device Transistors:	1990
D. Fabrication Location:	Oregon, USA
E. Assembly Location:	Korea, Thailand, Malaysia or Philippines
F. Date of Initial Production:	April, 1998

III. Packaging Information

A. Package Type:	**16-Lead QSOP**
B. Lead Frame:	Copper
C. Lead Finish:	Solder Plate
D. Die Attach:	Silver-filled epoxy
E. Bondwire:	Gold (1.3 mil dia.)
F. Mold Material:	Epoxy with silica filler
G. Bonding Diagram	05-1701-0312
H. Flammability Rating:	Class UL94-V0

I. Classification of Moisture Sensitivity per JEDEC standard JESD22-A112: Level 1

IV. Die Information

A. Dimensions:	107 x 80 mils
B. Passivation:	Si_3N_4/SiO_2 (Silicon nitride/ Silicon dioxide)
C. Interconnect:	Aluminum
D. Backside Metallization:	None
E. Minimum Metal Width:	1.2 microns (as drawn)
F. Minimum Metal Spacing:	1.2 microns (as drawn)
G. Bondpad Dimensions:	5 mil. Sq.
H. Isolation Dielectric:	SiO_2
I. Die Separation Method:	Wafer Saw

V. Quality Assurance Information

A. Quality Assurance Contacts: Jim Pedicord (Reliability Lab Manager
Bryan Preeshl (Executive Director of QA)
Kenneth Huening (Vice President)

B. Outgoing Inspection Level: 0.1% for all electrical parameters guaranteed by the Datasheet.
0.1% For all Visual Defects.

C. Observed Outgoing Defect Rate: < 50 ppm

D. Sampling Plan: Mil-Std-105D

VI. Reliability Evaluation

A. Accelerated Life Test

The results of the 135°C biased (static) life test are shown in **Table 1**. Using these results, the Failure Rate (λ) is calculated as follows:

$$\lambda = \frac{1}{MTTF} = \frac{4.04}{192 \times 4389 \times 80 \times 2}$$

(Chi square value for MTTF upper limit)

Temperature Acceleration factor assuming an activation energy of 0.8eV

$\lambda = 29.97 \times 10^{-9}$ $\lambda =$ 29.97 F.I.T. (60% confidence level @ 25°C)

This low failure rate represents data collected from Maxim's reliability qualification and monitor programs. Maxim also performs weekly Burn-In on samples from production to assure reliability of its processes. The reliability required for lots which receive a burn-in qualification is 59 F.I.T. at a 60% confidence level, which equates to 3 failures in an 80 piece sample. Maxim performs failure analysis on rejects from lots exceeding this level. The attached Burn-In Schematic (Spec. # 06-5048) shows the static circuit used for this test. Maxim also performs 1000 hour life test monitors quarterly for each process. This data is published in the Product Reliability Report (**RR-1M**).

B. Moisture Resistance Tests

Maxim evaluates pressure pot stress from every assembly process during qualification of each new design. Pressure Pot testing must pass a 20% LTPD for acceptance. Additionally, industry standard 85°C/85%RH or HAST tests are performed quarterly per device/package family.

C. E.S.D. and Latch-Up Testing

The PW86 die type has been found to have all pins able to withstand a transient pulse of ±2000V, per Mil-Std-883 Method 3015 (reference attached ESD Test Circuit). Latch-Up testing has shown that this device withstands a current of ±250mA and/or ±20V.

Table 1
Reliability Evaluation Test Results

MAX1652EEE

TEST ITEM	TEST CONDITION	FAILURE IDENTIFICATION	PACKAGE	SAMPLE SIZE	NUMBER OF FAILURES
Static Life Test (Note 1)					
	Ta = 135°C Biased Time = 192 hrs.	DC Parameters & functionality		80	1
Moisture Testing (Note 2)					
Pressure Pot	Ta = 121°C P = 15 psi. RH= 100% Time = 168hrs.	DC Parameters & functionality	QSOP	740	0
85/85	Ta = 85°C RH = 85% Biased Time = 1000hrs.	DC Parameters & functionality		77	0
Mechanical Stress (Note 2)					
Temperature Cycle	-65°C/150°C 1000 Cycles Method 1010	DC Parameters		77	0

Note 1: Life Test Data may represent plastic D.I.P. qualification lots.
Note 2: Generic package/process data

Attachment #1

TABLE II. Pin combination to be tested. 1/ 2/

	Terminal A (Each pin individually connected to terminal A with the other floating)	Terminal B (The common combination of all like-named pins connected to terminal B)
1.	All pins except V_{PS1} 3/	All V_{PS1} pins
2.	All input and output pins	All other input-output pins

1/ Table II is restated in narrative form in 3.4 below.
2/ No connects are not to be tested.
3/ Repeat pin combination I for each named Power supply and for ground

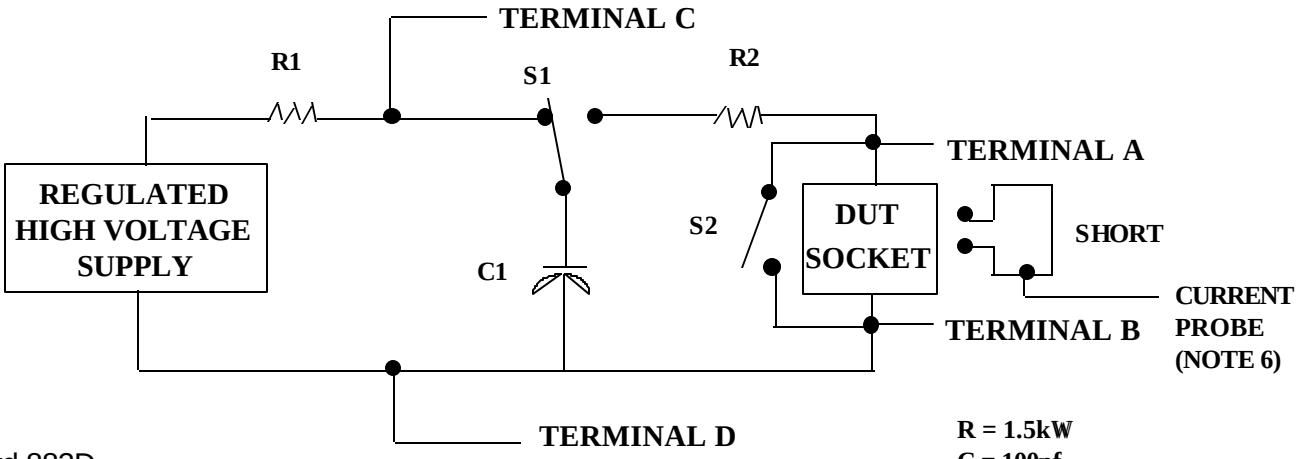
(e.g., where V_{PS1} is V_{DD}, V_{CC}, V_{SS}, V_{BB}, GND, $+V_S$, $-V_S$, V_{REF}, etc).

3.4 Pin combinations to be tested.

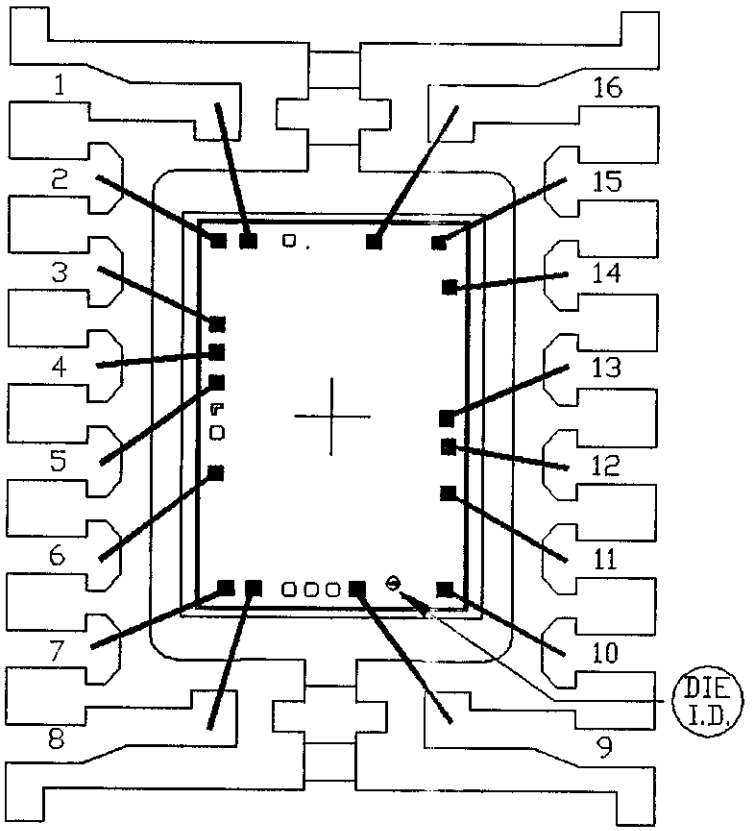
a. Each pin individually connected to terminal A with respect to the device ground pin(s) connected to terminal B. All pins except the one being tested and the ground pin(s) shall be open.

b. Each pin individually connected to terminal A with respect to each different set of a combination of all named power supply pins (e.g., V_{SS1}, or V_{SS2} or V_{SS3} or V_{CC1}, or V_{CC2}) connected to terminal B. All pins except the one being tested and the power supply pin or set of pins shall be open.

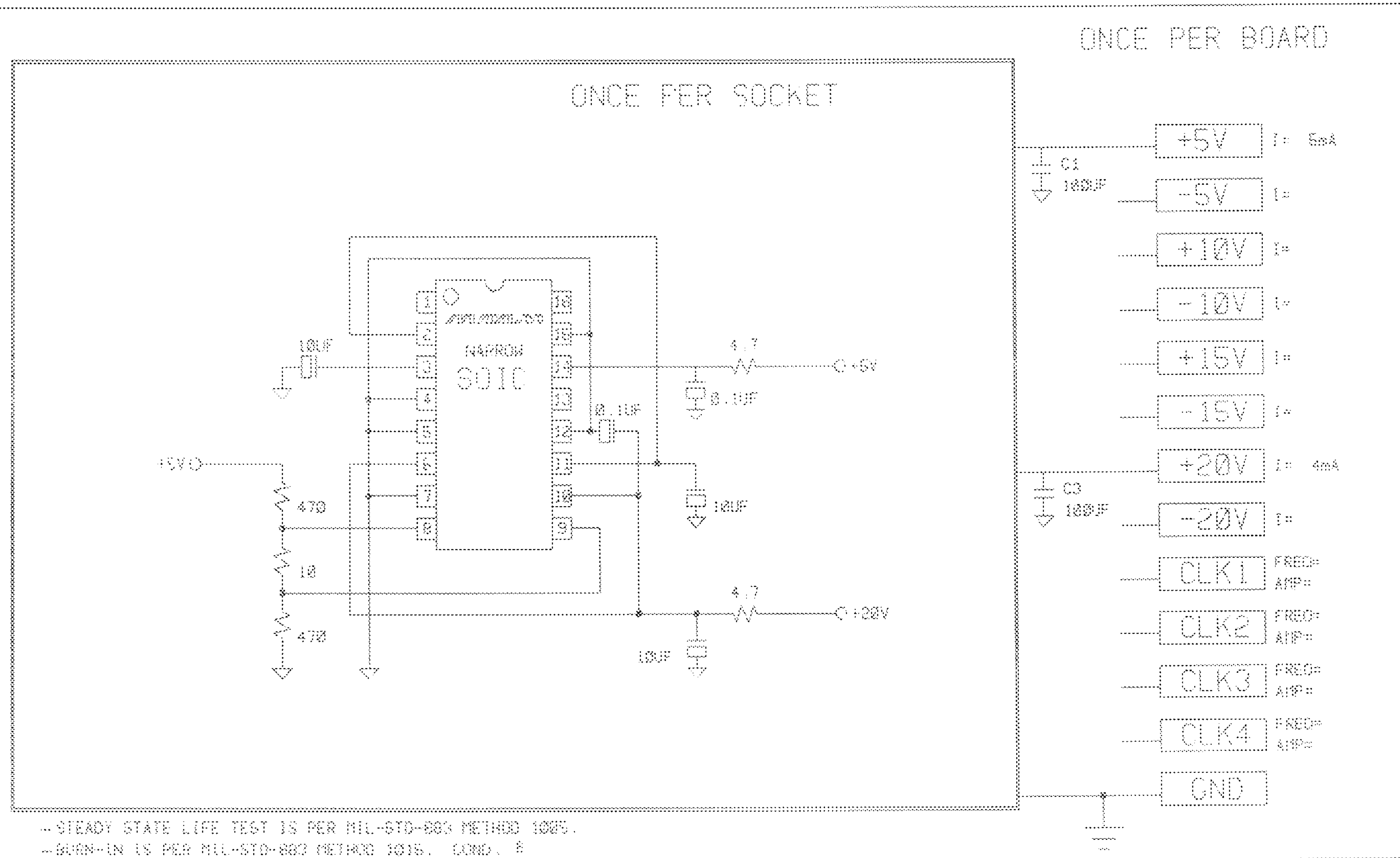
c. Each input and each output individually connected to terminal A with respect to a combination of all the other input and output pins connected to terminal B. All pins except the input or output pin being tested and the combination of all the other input and output pins shall be open.



Mil Std 883D
Method 3015.7
Notice 8



PKG.CODE: E16-1		APPROVALS	DATE	MAXIM
CAV./PAD SIZE: 96X130	PKG. DESIGN			BUILDSHEET NUMBER: 05-1701-0312 / REV.: A



--STEADY STATE LIFE TEST IS PER MIL-STD-883 METHOD 1005.
--BURN-IN IS PER MIL-STD-883 METHOD 1015. COND. B

NOTES:

1. TEMPERATURE: 125C OR EQUIVALENT
2. TIME: 160 HOURS MIN. OR EQUIVALENT
3. ALL COMPONENTS AND MATERIAL MUST STAND 150C CONTINUOUS
4. APPROVED FOR [X] COMMERCIAL
   [X] HR/883

SPEC. NO. 06-5048 REV. B

DATE: 9/22/94

DRAWN BY:

MAXIM BURN-IN SCHEMATIC

DEVICE TYPE: MAX736/737/738 MAX1652/3/4/5